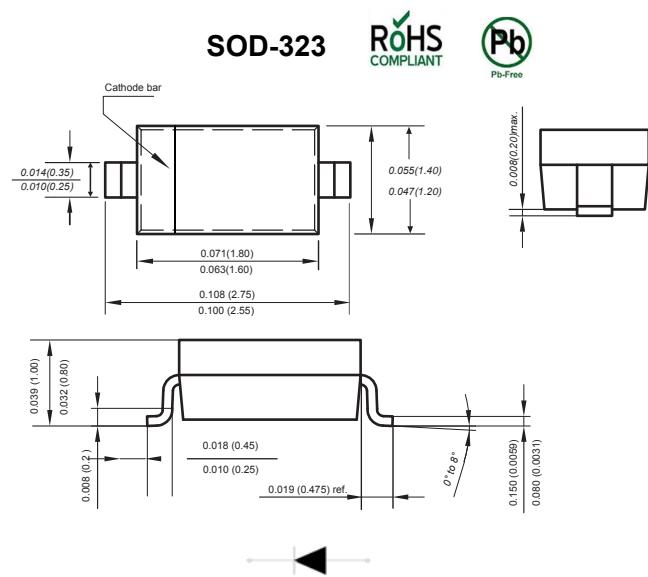


Features

- High current rectifier Schottky diodes
- Low voltage, low inductance
- For detection and step-up-conversion

Mechanical Data

- Case: SOD-323
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 5.48mg / 0.00019oz



Dimensions in inches and (millimeters)

Maximum Ratings Ta=25 °C

Parameter	Symbols	BAT60B	Units
Non-repetitive Peak Reverse Voltage	V _{RRM}	10	V
Forward Current	I _F	3	A
Forward Surge Current at 8.3ms	I _{FSM}	20	A
Power Dissipation at T _c =25°C	P _D	350	mW
Operating and Storage Temperature Range	T _j , T _{stg}	-55 ~ +150	°C

ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

Parameter	Symbols	BAT60B	Units
Maximum Forward Voltage I _F =10 mA I _F =100 mA I _F = 500 mA I _F =1000 mA	V _F	0.30 0.38 0.50 0.60	V
Peak Reverse Current V _{R1} =5V V _{R2} =8V	I _R	15 20	µA
Diodes Capacitance V _R =5V,f=1MHz	C _T	30	pF

Characteristic Curves ($T_A=25^\circ\text{C}$ unless otherwise noted)

Fig.1 Power Derating Curve

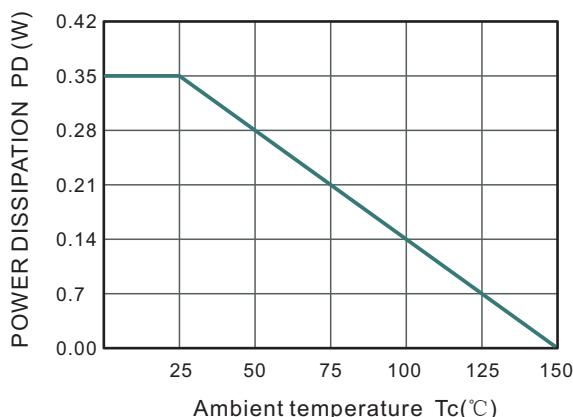


Fig.2 Typical Reverse Characteristics

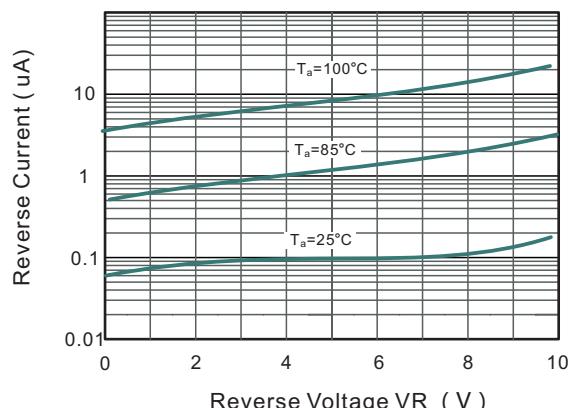


Fig.3 Typical Junction Capacitance

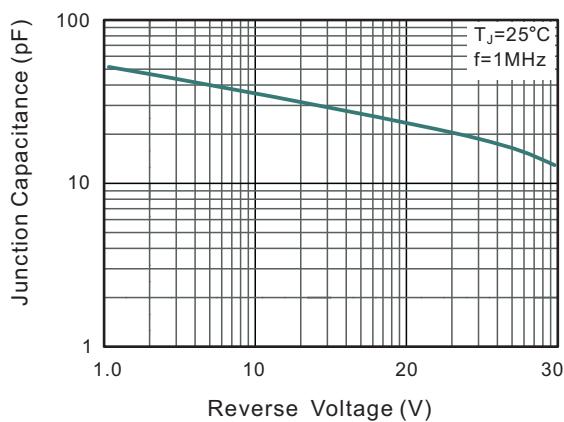


Fig.4 Typical Forward Characteristic

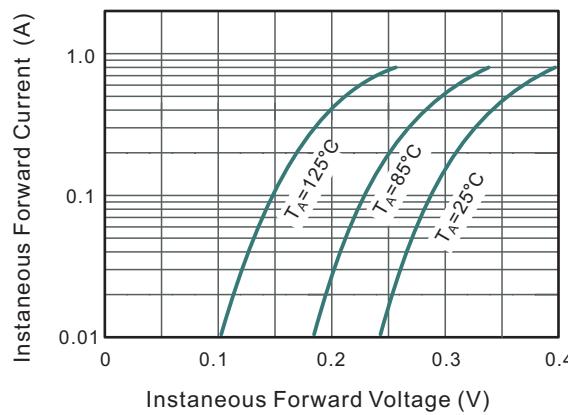
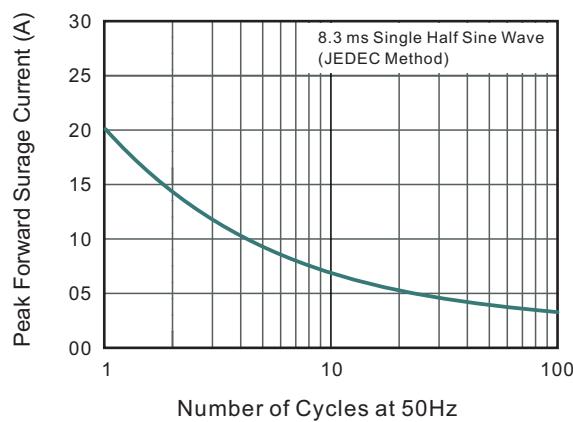
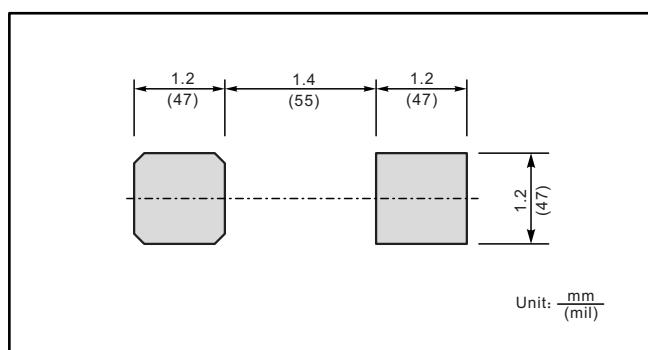


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current



The recommended mounting pad size

**Marking**

Type number	Marking code
BAT60B	W5 OR 5